Zibo Seno Electronic Engineering Co., Ltd.



B40C800DM B80C800DM B125C800DM B250C800DM B380C800DM

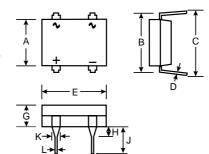




1.0A SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIER

Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Surge Current Capability
- Designed for Surface Mount Application
- Plastic Material UL Recognition Flammability Classification 94V-O



| DFM | | | | | | |
|----------------------|------|------|--|--|--|--|
| Dim | Min | Max | | | | |
| Α | 6.20 | 6.50 | | | | |
| В | 6.80 | 8.40 | | | | |
| С | 7.24 | 8.70 | | | | |
| D | 0.20 | 0.38 | | | | |
| E | 8.12 | 8.80 | | | | |
| G | 2.15 | 3.40 | | | | |
| Н | 1.30 | - | | | | |
| J | 3.80 | 4.90 | | | | |
| K | 0.90 | 1.40 | | | | |
| L | 0.45 | 0.58 | | | | |
| М | 5.00 | 5.20 | | | | |
| All Dimensions in mm | | | | | | |

Mechanical Data

Case: DFM, Molded Plastic

 Terminals: Plated Leads Solderable per MIL-STD-202, Method 208

Polarity: As Marked on Case

• Weight: 0.38 grams (approx.) atasheet.com

Mounting Position: AnyMarking: Type Number

Lead Free: For RoHS / Lead Free Version

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic | Symbol | B40 C800DM | B80 C800DM | B125 C800DM | B250 C800DM | B380 C800DM | Unit |
|---|--------------------|---------------|---------------|----------------|----------------|----------------|----------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | Vrrm Vrwm Vr | 100 | 200 | 400 | 600 | 1000 | ٧ |
| RMS Reverse Voltage | VR(RMS) | 40 | 80 | 125 | 250 | 380 | V |
| Average Rectified Output Current @T _A = 40°C | lo | 1.0 | | | | | Α |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method) | IFSM | 50 | | | | | А |
| Forward Voltage per element @I _F = 1.0A | VFM | 0.98 | | | | | ٧ |
| | lгм | 2.0 500 | | | | | μΑ |
| Typical Junction Capacitance per element (Note 1) | Cj | 25 | | | | | pF |
| Typical Thermal Resistance per leg (Note 2) | RθJA RθJL | 40 15 | | | | | °C/W |
| Operating and Storage Temperature Range | Тј, Тѕтс | -55 to +150 | | | | | °C |

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

2. Mounted on PC board with 13mm² copper pad.

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0.01

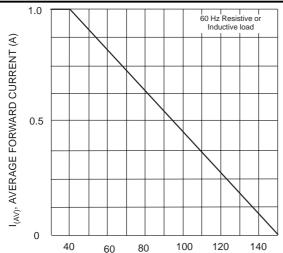
0.4





1.4

1.2

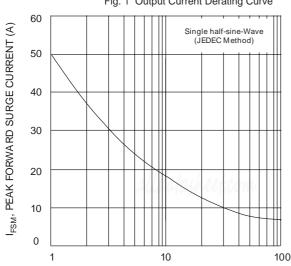


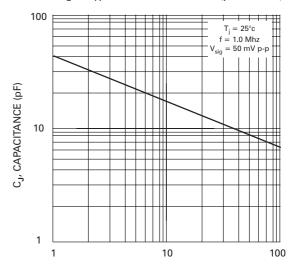
I_F, INSTANTANEOUS FORWARD CURRENT (A) $T_i = 25^{\circ}C$ Pulse Width = 300μ s 2% duty cycle 1.0 0.1

T_A, AMBIENT TEMPERATURE (°C) Fig. 1 Output Current Derating Curve

V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typ Forward Characteristics (per element)

1.0





NUMBER OF CYCLES AT 60 Hz Fig. 3 Max Non-Repetitive Peak Forward Surge Current

V_R, REVERSE VOLTAGE (V) Fig. 4 Typ Junction Capacitance (per element)



